

6MBI225V-120-50

IGBT Modules

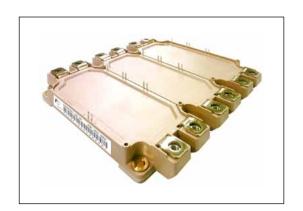
IGBT MODULE (V series) 1200V / 225A / 6 in one package

■ Features

Compact Package P.C.Board Mount Low VcE (sat) **RoHS** Compliant product

■ Applications

Inverter for Motor Drive AC and DC Servo Drive Amplifier Uninterruptible Power Supply Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items			Symbols	Conditions		Maximum ratings	Units	
	Collector-Emitter voltage		Vces				V	
nverter	Gate-Emitter voltage		V _{GES}			±20	V	
	Collector current		Ic	Continuous	Tc=25°C	300		
			I _{cp}		Tc=100°C	225		
			I _{c pulse}	1ms		450	Α	
_			-Ic			225		
			-Ic pulse	1ms		450		
	Collector power dissipation		Pc	1 device		1070	W	
Junction temperature		T _j			175			
Operation temperature (under switching conditions)		T _{jop}			150	°C		
Case temperature		Tc			125	C		
Storage temperature		T _{stg}			-40 to +125			
Isc	olation voltage 💳	between terminal and copper base (*1)	- V _{iso}	AC : 1min.		2500	VAC	
		between thermistor and others (*2)	Viso			2500	VAC	
80	crew torque	Mounting (*3)	-			3.5	N m	
SC		Terminals (*4)	-			4.5	IN III	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value : 2.5-3.5 Nm (M5)

Note *4: Recommendable value : 3.5-4.5 Nm (M6)

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● Electrical characteristics (at Tj= 25°C unless otherwise specified)

Items		Cymhala	Conditions		Characteristics			Units
		Symbols			min.	typ.	max.	Units
Inverter	Zero gate voltage collector current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	3.0	mA
	Gate-Emitter leakage current	Iges	$V_{GE} = 0V$, $V_{GE} = \pm 20V$		-	-	600	nA
	Gate-Emitter threshold voltage	V _{GE (th)}	V _{CE} = 20V, I _C = 225mA		6.0	6.5	7.0	V
		V _{CE (sat)} (terminal)	V _{GE} = 15V I _C = 225A	Tj=25°C	-	2.20	2.65	V
	Collector-Emitter saturation voltage			Tj=125°C	-	2.55	-	
				Tj=150°C	-	2.60	-	
		V _{CE (sat)} (chip)	V _{GE} = 15V I _C = 225A	Tj=25°C	-	1.85	2.30	
				Tj=125°C	-	2.20	-	
				Tj=150°C	-	2.25	-	
	Internal gate resistance	R _{G(int)}	-		-	3.33	-	Ω
	Input capacitance	Cies	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz		-	18	-	nF
		ton	1/ 0001/	-	550	-	nsec	
	Turn-on time	tr	V _{cc} = 600V I _c = 225A	-	180	-		
		tr (i)	V _{GE} = ±15V	-	120	-		
		toff	$R_G = 1.6\Omega$	-	1050	-		
	Turn-off time	tf	LS=80nH		-	110		-
		V _F (terminal)	V _{GE} = 0V I _F = 225A	Tj=25°C	-	2.05	2.50	V
	Forward on voltage			Tj=125°C	-	2.20	-	
				Tj=150°C	-	2.15	-	
		V _F (chip)	V _{GE} = 0V I _F = 225A	Tj=25°C	-	1.70	2.15	
				Tj=125°C	-	1.85	-	
				Tj=150°C	-	1.80	_	1
	Reverse recovery time	trr	I _F = 225A		-	200	-	nsec
ō		_	T = 25°C		-	5000	-	Ω
Thermistor	Resistance	R	T = 100°C		465	495	520	
The	B value	В	T = 25 / 50°C		3305	3375	3450	K

● Thermal resistance characteristics

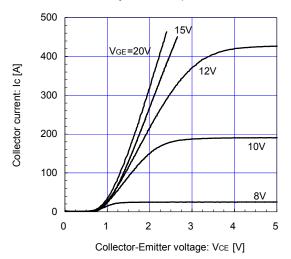
Items	Symbols	Conditions	Characteristics			Units
items		Conditions	min.	typ.	max.	Units
Thormal registance (Adevice)	R _{th(j-c)}	Inverter IGBT	-	-	0.140	°C/W
Thermal resistance (1device)		Inverter FWD	-	-	0.190	
Contact thermal resistance (1device) (*5)	R _{th(c-f)}	with Thermal Compound	-	0.0167	-	

Note $^{\star}5$: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Characteristics (Representative)

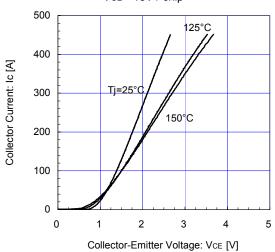
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 25°C / chip



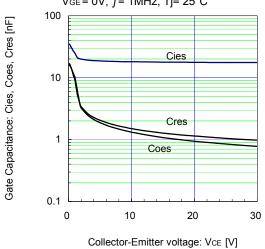
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) V_{GE}= 15V / chip



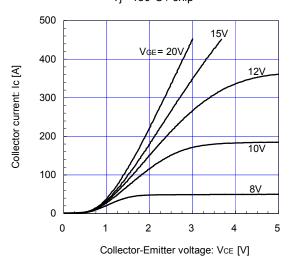
[INVERTER]

Gate Capacitance vs. Collector-Emitter Voltage (typ.) $V_{GE} = 0V$, f = 1MHz, $T_{j} = 25$ °C



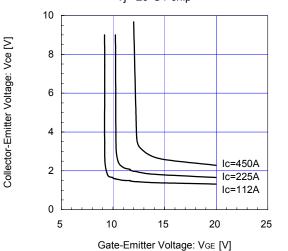
[INVERTER]

Collector current vs. Collector-Emitter voltage (typ.) Tj= 150°C / chip



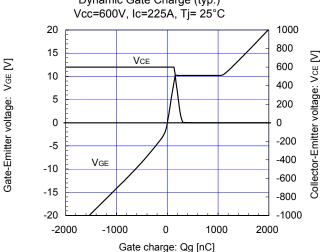
[INVERTER]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.) Tj= 25°C / chip



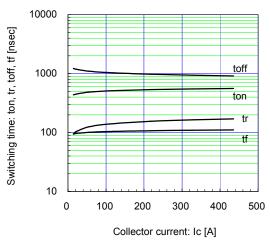
[INVERTER]

Dynamic Gate Charge (typ.)



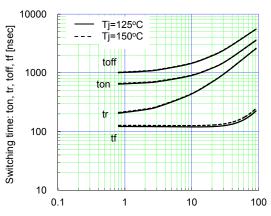
[INVERTER]

Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.6 Ω , Tj=25°C



[INVERTER]

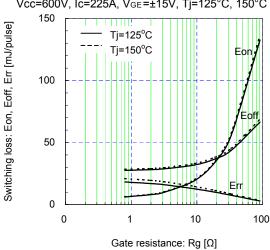
Switching time vs. Gate resistance (typ.) Vcc=600V, Ic=225A, V $_{GE}$ =±15V, Tj=125°C, 150°C



[INVERTER]

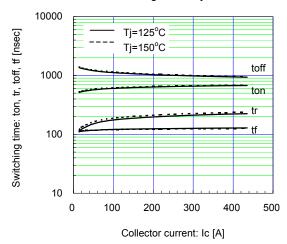
Gate resistance: Rg $[\Omega]$

Switching loss vs. Gate resistance (typ.) Vcc=600V, Ic=225A, V_{GE}=±15V, Tj=125°C, 150°C



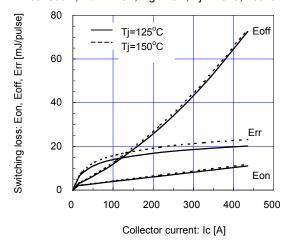
[INVERTER]

Switching time vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.6 Ω , Tj=125°C, 150°C



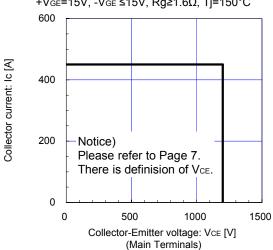
[INVERTER]

Switching loss vs. Collector current (typ.) Vcc=600V, VgE= \pm 15V, Rg=1.6 Ω , Tj=125°C, 150°C

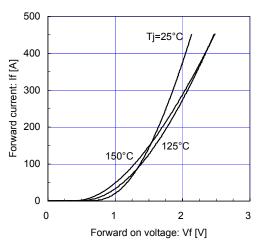


[INVERTER]

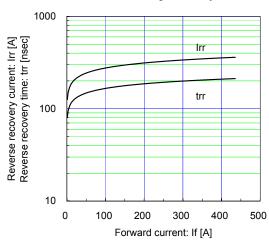
Reverse bias safe operating area (max.) +V_{GE}=15V, -V_{GE}≤15V, Rg≥1.6Ω, Tj=150°C



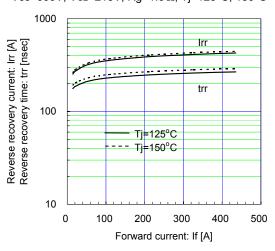
[INVERTER] Forward Current vs. Forward Voltage (typ.) chip



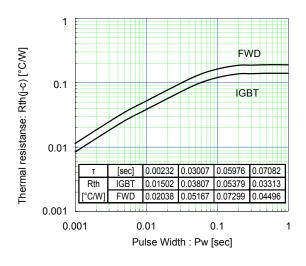
[INVERTER] Reverse Recovery Characteristics (typ.) Vcc=600V, VGE=±15V, Rg=1.6 Ω, Tj=25°C



[INVERTER] Reverse Recovery Characteristics (typ.) Vcc=600V, V_{GE}=±15V, Rg=1.6 Ω, Tj=125°C, 150°C

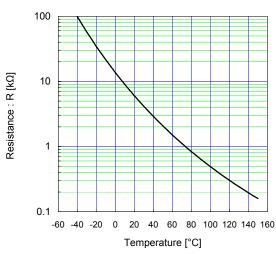


Transient Thermal Resistance (max.)

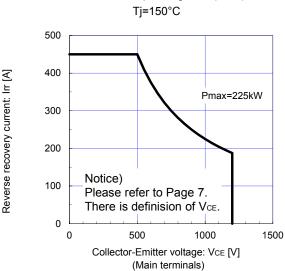


[THERMISTOR]

Temperature characteristic (typ.)



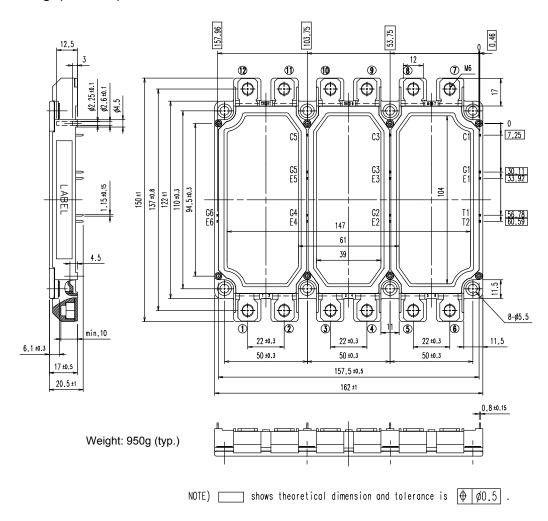
FWD safe operating area (max.)



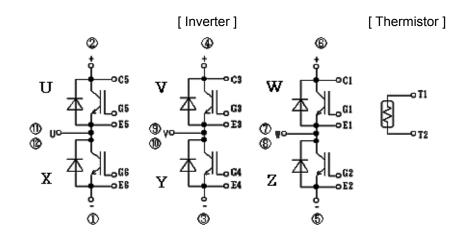
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■ Outline Drawings(Unit:mm)

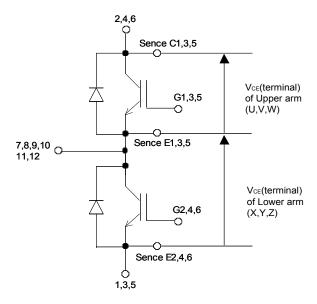


■ Equivalent Circuit



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■ Definition of switching characteristics



Switching characteristics of V_{CE} is defined between Sense C1,3,5 and Sense E1,3,5 for Upper arm(U,V,W) and Sense E1,3,5 and Sense E2,4,6 for Lower arm(X,Y,Z) .

Please use these terminals whenever measure spike voltage.

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- Measurement equipment

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- Safety devices
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